

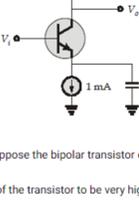
ANALOG CIRCUITS-2 (GATE - 2021) - REPORTS

OVERALL ANALYSIS COMPARISON REPORT **SOLUTION REPORT**

ALL(17) CORRECT(7) INCORRECT(4) SKIPPED(6)

Q. 1 [FAQ](#) [Solution Video](#) [Have any Doubt ?](#)

Consider the circuit shown in the figure below:



Suppose the bipolar transistor exhibits the following characters $I_C = I_s \exp\left(\frac{V_{BE}}{2V_T}\right)$. Assuming the

β of the transistor to be very high on no early effect the value of small signal gain of the amplifier is equal to (Assume $V_T = 25$ mV)

- A 20
 B 40
 C -20
 D -40

Correct Option

Solution :
 (c)

$$\delta_m = \frac{\partial I_C}{\partial V_{BE}} = \frac{I_C}{2V_T} = \frac{1 \times 10^{-3}}{2 \times 25 \times 10^{-3}} = \frac{1}{50} = 20 \text{ mA/V}$$

$$\therefore A_p = -\delta_m R_C = -20 \text{ mA/V} \times 1 \text{ k}\Omega = -20 \text{ V/V}$$

D -40

Your answer is Wrong

[QUESTION ANALYTICS](#)

Q. 2 [FAQ](#) [Solution Video](#) [Have any Doubt ?](#)

In a differential amplifier if the emitter resistance is replaced by an ideal current source then

- A the differential gain of the amplifier is increased
 B the common mode gain of the amplifier decreased
 C the CMRR of the amplifier is reduced
 D the CMRR of the amplifier remains unaffected

Your answer is Correct

Solution :
 (b)

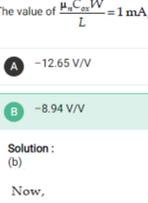
C the CMRR of the amplifier is reduced

D the CMRR of the amplifier remains unaffected

[QUESTION ANALYTICS](#)

Q. 3 [Solution Video](#) [Have any Doubt ?](#)

Consider the circuit shown in the figure below:



The value of $\frac{I_{DQ} C_{ox} W}{L} = 1 \text{ mA/V}$, $V_T = 2 \text{ V}$ and $\lambda = 0$. Then, the value of small signal voltage gain A_v is equal to

- A -12.65 V/V
 B -8.94 V/V
 C -16.31 V/V
 D -21.22 V/V

Your answer is Correct

Solution :
 (b)

Now,

$$g_m = \sqrt{2I_{DQ} C_{ox} \frac{W}{L} I_{DS}} = \sqrt{2 \times 1 \times 10^{-3} \times 0.4 \times 10^{-3}}$$

Thus,

$$A_v = -g_m R_D = -0.894 \times 10 = -8.94 \text{ V/V}$$

C -16.31 V/V

D -21.22 V/V

[QUESTION ANALYTICS](#)

Q. 4 [Solution Video](#) [Have any Doubt ?](#)

Consider a two stage amplifier circuit shown in the figure below:

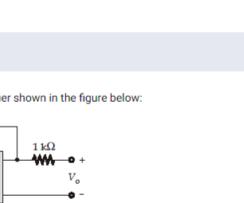


The transconductance of the transistor T_1 and T_2 are δ_{m1} and δ_{m2} respectively, then the overall transconductance $g_m = \frac{I_o}{V_i}$ is equal to (Assume $\alpha_1 = \alpha_2 = 1$)

- A $\delta_m \approx \delta_{m1}$
 B $\delta_m \approx \delta_{m1} + \delta_{m2}$
 C $\delta_m \approx \delta_{m2}$
 D $\delta_m \approx \delta_{m1} - \delta_{m2}$

Your answer is Correct

Solution :
 (a)



Now,

$$I_o = \frac{I_1}{\alpha} \approx I_1$$

\therefore

$$g_m = \frac{I_o}{V_i} \approx \frac{I_1}{V_i} = \delta_{m1}$$

B $\delta_m \approx \delta_{m1} + \delta_{m2}$

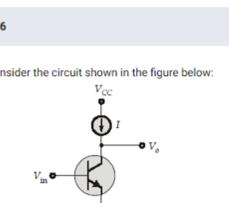
C $\delta_m \approx \delta_{m2}$

D $\delta_m \approx \delta_{m1} - \delta_{m2}$

[QUESTION ANALYTICS](#)

Q. 5 [FAQ](#) [Solution Video](#) [Have any Doubt ?](#)

Consider an ideal voltage amplifier shown in the figure below:



The value of input pole frequency is equal to

- A 23.16 Hz
 B 15.91 Hz
 C 59.99 Hz
 D 88.69 Hz

Your answer is Correct

Solution :
 (b)

The capacitance at the input

$$C_{in} = C_1(1 + A_v) = 1 \times 10^{-9}(1 + 10^3)$$

\therefore

$$C_{in} \approx 1 \times 10^{-6} \text{ F}$$

\therefore

$$\tau = RC_{in} = 10 \times 10^3 \times 1 \times 10^{-6} = 10^{-2}$$

\therefore

$$\omega_{in} = \frac{1}{\tau} = 100 \text{ rad/sec}$$

\therefore

$$f_{in} = \frac{100}{2\pi} = 15.91 \text{ Hz}$$

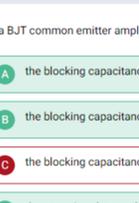
C 59.99 Hz

D 88.69 Hz

[QUESTION ANALYTICS](#)

Q. 6 [FAQ](#) [Solution Video](#) [Have any Doubt ?](#)

Consider the circuit shown in the figure below:



The circuit is biased by an ideal current source with current I. The value of β for the transistor is very large and $\eta = 1$. If the small signal voltage gain for the transistor is equal to $|A_v| = 50$ and the output impedance is equal to 10 k Ω , then the value of DC biasing current I is equal to ____ μA . (Assume $V_T = 26$ mV)

- A 130
 B 130
 C 130
 D 130

Your answer is Correct

Solution :
 130

Given: $r_o = 10 \text{ k}\Omega$

$$|A_v| = g_m r_o = \frac{I_C}{V_T} r_o$$

$$50 = \frac{I_C}{26 \text{ mV}} \times 10 \text{ k}\Omega$$

$$I_{DC} = 130 \mu\text{A}$$

[QUESTION ANALYTICS](#)

Q. 7 [Solution Video](#) [Have any Doubt ?](#)

An amplifier has open loop gain of $A_{OL} = 5 \times 10^3$. The amplifier is connected by the negative feedback with feedback factor $\beta = 0.01$. If the open loop gain of op-amp decreases by 10%, then the closed loop gain decreased by ____ %.

- A 0.19 (0.18 - 0.25)
 B 0.19 (0.18 - 0.25)
 C 0.19 (0.18 - 0.25)
 D 0.19 (0.18 - 0.25)

Correct Option

Solution :
 0.19 (0.18 - 0.25)

$$\% \text{ Change} = \frac{10\%}{1 + 5 \times 10^3 \times 10^{-2}} = \frac{10\%}{51} = 0.19\%$$

B 0.19 (0.18 - 0.25)

Your Answer is 0.48

[QUESTION ANALYTICS](#)

Q. 8 [FAQ](#) [Solution Video](#) [Have any Doubt ?](#)

In a BJT common emitter amplifier,

- A the blocking capacitance at the input is called as input coupling capacitor. Your option is Correct
 B the blocking capacitance at the output is called as output coupling capacitor. Your option is Correct
 C the blocking capacitance at the emitter is called as bypass capacitor. Your answer is Wrong
 D the capacitor that produces on A.C ground is called as bypass capacitor. Your option is Correct

YOUR ANSWER - d,a,b,c CORRECT ANSWER - a,b,d STATUS - ✖

Solution :

[QUESTION ANALYTICS](#)

Q. 9 [Solution Video](#) [Have any Doubt ?](#)

The desirable characteristics of a transconductance amplifier are

- A high input resistance Your option is Correct
 B high output resistance Your option is Correct
 C low input resistance
 D low output resistance

YOUR ANSWER - a,b CORRECT ANSWER - a,b STATUS - ✔

Solution :

[QUESTION ANALYTICS](#)

Q. 10 [Solution Video](#) [Have any Doubt ?](#)

Consider the circuit shown in the figure below:

The amplifier has common emitter input resistance equal to r_{in} and current gain β , then the value of the output resistance R_{out} is equal to

- A R_L
 B $R_L \parallel \left(\frac{r_{in}}{\beta + 1} \right)$
 C $R_L \parallel r_{in}$
 D $\left(\frac{1}{R_L} \parallel \frac{1}{r_{in}} \right)^{-1}$

Your answer is Correct

Solution :
 (b)

and

$$I_o = \frac{V_o}{R_L} = \frac{V_o}{R_L} - \beta I_b$$

\therefore

$$I_b = -\frac{V_o}{r_{in}}$$

\therefore

$$I_o = \frac{V_o}{R_L} + \frac{V_o}{R_L} + \beta \frac{V_o}{r_{in}}$$

\therefore

$$R_o = \frac{V_o}{I_o} = R_L \parallel \frac{r_{in}}{(\beta + 1)}$$

C $R_L \parallel r_{in}$

D $\left(\frac{1}{R_L} \parallel \frac{1}{r_{in}} \right)^{-1}$

[QUESTION ANALYTICS](#)

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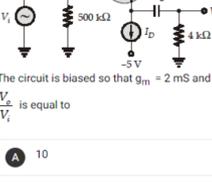
OVERALL ANALYSIS COMPARISON REPORT **SOLUTION REPORT**

ALL(17) CORRECT(7) INCORRECT(4) SKIPPED(6)

Q. 11

[Solution Video](#) [Have any Doubt ?](#)

Consider the source-follower circuit shown below:



The circuit is biased so that $g_m = 2 \text{ mS}$ and the value of output resistance for MOS transistor $r_o = 100 \text{ k}\Omega$, then the value of small signal voltage gain $\frac{V_o}{V_i}$ is equal to

A 10

B -0.8

Your answer is **Wrong**

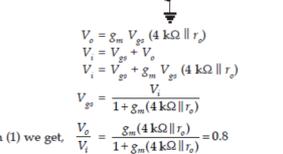
C 0.8

Correct Option

Solution :

(c)

The value of small signal equivalent is shown in the figure below:



Now,

$$V_o = g_m V_{gs} (4 \text{ k}\Omega \parallel r_o) \quad \dots(1)$$

Now,

$$V_i = V_{gs} + V_o$$

$$V_i = V_{gs} + g_m V_{gs} (4 \text{ k}\Omega \parallel r_o) \quad \dots(2)$$

$$V_{gs} = \frac{V_i}{1 + g_m(4 \text{ k}\Omega \parallel r_o)}$$

$$\therefore \text{Substituting (2) in (1) we get, } \frac{V_o}{V_i} = \frac{g_m(4 \text{ k}\Omega \parallel r_o)}{1 + g_m(4 \text{ k}\Omega \parallel r_o)} = 0.8$$

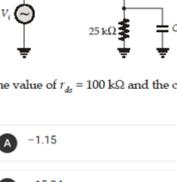
D -0.9

QUESTION ANALYTICS

Q. 12

[FAQ](#) [Solution Video](#) [Have any Doubt ?](#)

Consider the circuit shown in the figure below:



the value of $r_{be} = 100 \text{ k}\Omega$ and the circuit is biased such that $g_m = 5 \text{ mS}$, then the value of $\frac{V_o}{V_i}$ is equal to

A -1.15

B -15.24

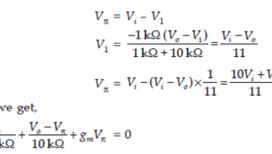
C -6.79

Correct Option

Solution :

(c)

Drawing the small signal equivalent, we get,



$$V_{\pi} = V_i - V_o$$

$$V_i = \frac{-1 \text{ k}\Omega (V_o - V_i)}{1 \text{ k}\Omega + 10 \text{ k}\Omega} = \frac{V_i - V_o}{11}$$

$$V_{\pi} = V_i - (V_i - V_o) \times \frac{1}{11} = \frac{10V_i + V_o}{11}$$

Applying KCL, we get,

$$\frac{V_o}{10 \text{ k}\Omega} + \frac{V_o}{100 \text{ k}\Omega} + \frac{V_o - V_{\pi}}{10 \text{ k}\Omega} + g_m V_{\pi} = 0$$

$$\frac{V_o - V_{\pi}}{10 \text{ k}\Omega} = \frac{V_o}{10 \text{ k}\Omega} + \frac{V_o}{100 \text{ k}\Omega} + \frac{5}{10^3} V_{\pi}$$

$$10(V_o - V_{\pi}) = 10V_o + V_o + 500V_{\pi}$$

$$21V_o = -490V_{\pi}$$

$$\frac{-21}{490} V_o = \frac{10V_i + V_o}{11}$$

$$\frac{-21}{490} V_o - \frac{V_o}{11} = \frac{10V_i}{11}$$

$$\frac{-103}{770} V_o = \frac{10V_i}{11}$$

$$\frac{V_o}{V_i} = \frac{-700}{103} = -6.79$$

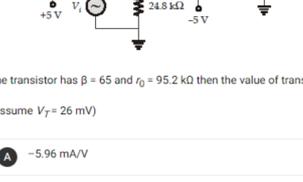
D -29.15

QUESTION ANALYTICS

Q. 13

[Solution Video](#) [Have any Doubt ?](#)

Consider the circuit shown in the figure below:



The transistor has $\beta = 65$ and $r_o = 95.2 \text{ k}\Omega$ then the value of transconductance $G = \frac{I_o}{V_i}$ is equal to (Assume $V_T = 26 \text{ mV}$)

A -5.96 mA/V

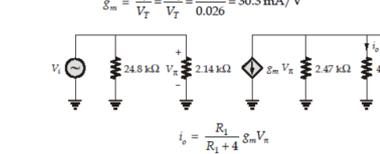
B -20.15 mA/V

C -11.6 mA/V

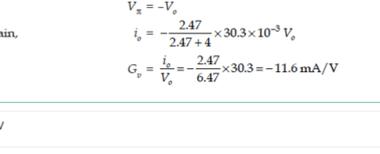
Correct Option

Solution :

(c)



$$g_m = \frac{i_c}{V_T} = \frac{\alpha i_e}{V_T} = \frac{0.788}{0.026} = 30.3 \text{ mA/V}$$



$$i_o = \frac{R_1}{R_1 + 4} g_m V_{\pi}$$

At input terminal, we have,

$$V_{\pi} = -V_o$$

So, we obtain,

$$i_o = \frac{2.47}{2.47 + 4} \times 30.3 \times 10^{-3} V_o$$

$$G = \frac{i_o}{V_o} = \frac{-2.47}{6.47} \times 30.3 = -11.6 \text{ mA/V}$$

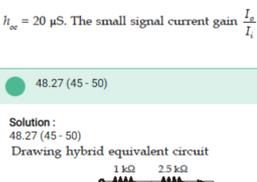
D -15.5 mA/V

QUESTION ANALYTICS

Q. 14

[Solution Video](#) [Have any Doubt ?](#)

Consider the BJT amplifier circuit as shown in the figure below:



The hybrid parameter of the transistor is given as $h_{fe} = 75$, $h_{ie} = 2.5 \text{ k}\Omega$, $h_{re} = 2.2 \times 10^{-4}$ and $h_{oe} = 20 \mu\text{S}$. The small signal current gain $\frac{I_o}{I_i}$ for the circuit in the midband region is _____.

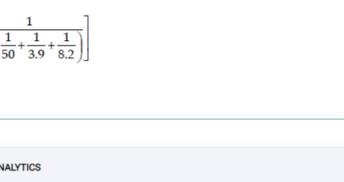
C 48.27 (45 - 50)

Correct Option

Solution :

48.27 (45 - 50)

Drawing hybrid equivalent circuit



$$I_o = h_{fe} I_i \left[\frac{1}{\frac{1}{h_{oe}} \parallel R_C \parallel R_L} \right]$$

$$\frac{I_o}{I_i} = 75 \left[\frac{1}{3.9 \left(\frac{1}{50} + \frac{1}{3.9} + \frac{1}{8.2} \right)} \right]$$

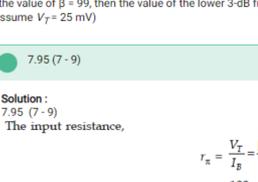
$$\frac{I_o}{I_i} = 48.27$$

QUESTION ANALYTICS

Q. 15

[Solution Video](#) [Have any Doubt ?](#)

Consider the common emitter circuit shown in the figure below:



If the value of $\beta = 99$, then the value of the lower 3-dB frequency is ____ Hz. (Assume $V_T = 25 \text{ mV}$)

C 7.95 (7 - 9)

Correct Option

Solution :

7.95 (7 - 9)

The input resistance,

$$r_{\pi} = \frac{V_T}{I_B} = \frac{\beta V_T}{I_C} = \frac{(\beta + 1) V_T}{I_E}$$

$$= \frac{100 \times 25 \times 10^{-3}}{1 \times 10^{-3}} = 2.5 \text{ k}\Omega$$

$$\therefore R_m = (20 \text{ k}\Omega \parallel 20 \text{ k}\Omega \parallel 2.5 \text{ k}\Omega) = 2 \text{ k}\Omega$$

$$\therefore f = \frac{1}{2\pi R_{eq} C_m} = \frac{1}{2\pi \times 10 \times 10^{-6} \times 2 \times 10^3} = 7.95 \text{ Hz}$$

QUESTION ANALYTICS

Q. 16

[FAQ](#) [Solution Video](#) [Have any Doubt ?](#)

A transistor amplifier circuit parameter at $I_C = 2 \text{ mA}$ has inner capacitance (emitter-base capacitance) $C_e = 1 \text{ pF}$, $C_{\pi} = 10 \text{ pF}$, $\beta = 150$ and $V_T = 25 \text{ mV}$. Then,

A the value of unity current gain cut-off frequency f_T is equal to 1.56 GHz

B the value of $f_{\beta} > f_T$.

C the value of f_{α} is equal to 1.165 GHz.

Correct Option

D the value of $f_{\alpha} > f_T$.

Correct Option

YOUR ANSWER - NA

CORRECT ANSWER - c,d

STATUS - SKIPPED

Solution :

(c,d)

$$g_m = \frac{I_C}{V_T} = \frac{2 \text{ mA}}{25 \text{ mV}} = 80 \times 10^{-3} \text{ A/V}$$

So, we obtain the unity gain frequency

$$f_T = \frac{g_m}{2\pi(C_e + C_{\pi})} = \frac{80 \times 10^{-3}}{2\pi(11) \times 10^{-12}} = 1.157 \text{ GHz}$$

$$f_{\beta} = \frac{f_T}{\beta} = 7.713 \text{ MHz}$$

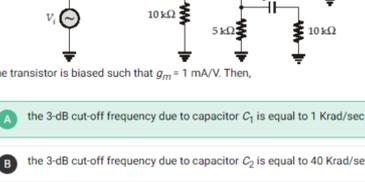
$$f_{\alpha} = f_T \times \alpha = 1.165 \text{ GHz}$$

QUESTION ANALYTICS

Q. 17

[FAQ](#) [Solution Video](#) [Have any Doubt ?](#)

Consider the circuit shown in the figure below:



The transistor is biased such that $g_m = 1 \text{ mA/V}$. Then,

A the 3-dB cut-off frequency due to capacitor C_1 is equal to 1 Krad/sec.

Correct Option

B the 3-dB cut-off frequency due to capacitor C_2 is equal to 40 Krad/sec.

C the 3-dB cut-off frequency due to capacitor C_3 is equal to 0.923 rad/sec.

D the 3-dB cut-off frequency of the amplifier due to capacitor C_3 is 923 rad/sec.

Correct Option

YOUR ANSWER - NA

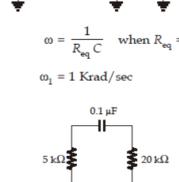
CORRECT ANSWER - a,d

STATUS - SKIPPED

Solution :

(a,d)

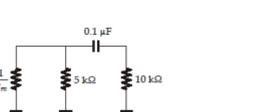
For the C_1 ,



$$\therefore \omega = \frac{1}{R_{eq} C} \text{ when } R_{eq} = 5 \text{ k}\Omega + 10 \text{ k}\Omega \parallel 10 \text{ k}\Omega$$

$$\therefore \omega_1 = 1 \text{ Krad/sec}$$

For capacitor C_2



$$\therefore \omega_2 = \frac{1}{R_2 C} = \frac{1}{25 \times 10^3 \times 0.1 \times 10^{-6}} = 400 \text{ rad/sec}$$

For capacitor C_3 , we have,



$$\therefore \omega_3 = \frac{1}{(1 \text{ k}\Omega \parallel 5 \text{ k}\Omega + 10 \text{ k}\Omega) \times 0.1 \times 10^{-6}}$$

$$\therefore \omega_3 = 923 \text{ rad/sec}$$

QUESTION ANALYTICS